

ST2051

Enhanced power switch

Not recommended for new design

Features

- 90 mΩ high-side MOSFET switch
- 500 mA continuous current per channel
- Thermal and short-circuit protection with overcurrent logic output
- Operating range from 2.7 to 5.5 V
- CMOS- and TTL-compatible enable inputs
- 2.5 ms typical rise time
- Undervoltage lock out
- 10 µA maximum standby supply current
- Ambient temperature range, 0 °C to 85 °C
- 2 kV ESD protection
- Fault-blanking

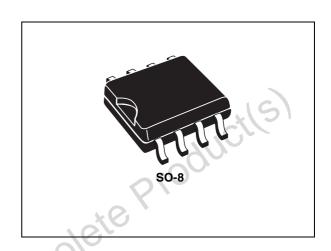


Table 1. Device summary

Order code	Package	Packaging
ST2051BDR ⁽¹⁾	SO-8	Tape and reel

Not recommended for new design (refer to STMPS2151MTR). Contact ST sales office for availability.

Description ST2051

1 Description

The ST2051 power distribution switch is intended for applications where heavy capacitive loads and short-circuits are likely to be encountered. These devices incorporate 90 m Ω N-channel MOSFET high-side power switches for power-distribution. The switch is controlled by a logic enable input. Gate drive is provided by an internal charge pump designed to control the power-switch rise times and fall times to minimize current surges during switching. The charge pump requires no external components and allows operation from supplies as low as 2.7 V.

When the output load exceeds the current-limit threshold or a short is present, the device limits the output current to a safe level by switching into a constant-current mode, pulling the overcurrent logic output low. When continuous heavy overloads and short-circuits increase the power dissipation in the switch, causing the junction temperature to rise, a thermal protection circuit shuts off the switch to prevent damage. Recovery from a thermal shutdown is automatic once the device has cooled sufficiently. Internal circuitry ensures the switch remains off until valid input voltage is present.



Schematic diagram and pin connections 2

Figure 1. Schematic diagram

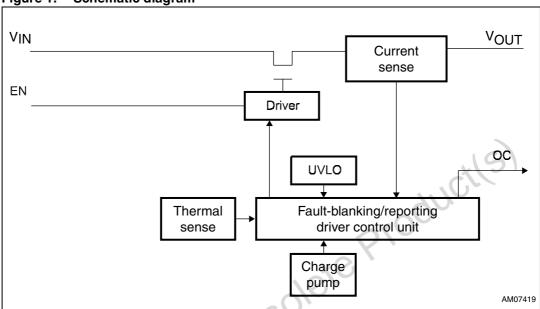
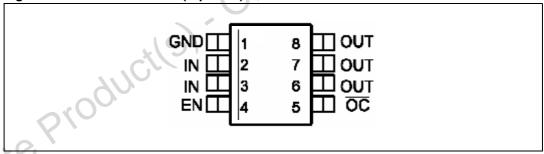


Figure 2. Pin connections (top view)



Pin functions

	· (C)			
7/6	Table 2.	Pin function	ns	
-MSO.	Pin	Name	Туре	Description
$O_{\mathcal{O}}$	1	GND	-	Ground
	2	IN1	-	V _{CC} input, 2.7-5.5 V
	3	IN2	-	V _{CC} input, 2.7-5.5 V
	4	EN	I	Enable (active hi)
	5	ОС	0	Open drain output for fault indication
	6	OUT3	-	Output
	7	OUT2	-	Output
	8	OUT1	-	Output

3 Functional descriptions

3.1 Fault-blanking

ST devices feature a 10 ms fault-blanking. Fault-blanking allows current-limit faults, including momentary short-circuit faults that occur when hot-swapping a capacitive load, and also ensures that no fault is issued during power-up. When a load transient causes the device to enter current limit, an internal counter starts. If the load fault persists beyond the 10 ms fault-blanking timeout, the FAULT output asserts low. Load-transient faults less than 10 ms (typical) will not cause a FAULT output assertion. Only current-limit faults are blanked. Die overtemperature faults and input voltage drops below the undervoltage lock out (UVLO) threshold will cause an immediate fault output.

3.2 Overcurrent/overtemperature protection

In overcurrent or short-circuit condition, the switch limits the current at 500 mA. If temperature of die goes above limit value, the switch turns OFF.

3.3 Undervoltage lock out (UVLO)

When input voltage drops below critical value, the power switch turns OFF to prevent improper operation due to low voltage.

ST2051 Maximum rating

4 Maximum rating

Stressing the device above the rating listed in the "Absolute maximum ratings" table may cause permanent damage to the device. These are stress ratings only, and operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Refer also to the STMicroelectronics™ SURE program and other relevant quality documents.

Table 3. Absolute maximum ratings

Symbol	Parameter	Value	Unit
VI	Input voltage range	-0.3-6.0	V
V _O	Output voltage range	-0.3-(V _I +0.3)	V
V _{IENX}	EN Input voltage range	-0.3-6.0	V
Io	Continuous output current	Internally limited	
ESD	ESD protection level	2	kV
TJ	Junction operating temperature	-40 to 125	°C
T _{STG}	Storage temperature	-55 to 150	°C

Table 4. Recommended operating conditions

	Symbol	Parameter	Min	Тур	Max	Unit
	VI	Input voltage	2.7	5.0	5.5	V
	V _O	Output voltage	0	5.0	5.5	V
	I _O	Continuous output current	0	-	500	mA
Obsole	ie P'					

Electrical characteristics ST2051

5 Electrical characteristics

Table 5. Electrical characteristics ($T_J = 25$ °C, $V_I = 5.0$ V)

Symbol	Parameter	Test conditions	Min	Тур	Max	Unit
		V _I = 3.3 V; -40 < T _J < 125 °C		100	145	
D	Static drain-source	V _I = 5.0 V; -40 < T _J < 125 °C		90	135	mΩ
R _{DS(on)}	on-state resistance	$V_I = 3.3 V;$ $T_J = 25 ^{\circ}C$		90	130	11152
		$V_I = 5.0 \text{ V};$ $T_J = 25 ^{\circ}\text{C}$		80	110) 1
	Output rise time ⁽¹⁾	$V_I = 5.5 \text{ V},$ $R_L = 10 \Omega,$ $C_L = 1 \mu\text{F}$	070	2.5		ms
t _r		$V_{I} = 2.7 \text{ V},$ $R_{L} = 10 \Omega,$ $C_{L} = 1 \mu\text{F}$		3		ms
+	Output fall time ⁽¹⁾	$V_{I} = 5.5 \text{ V},$ $R_{L} = 10 \Omega,$ $C_{L} = 1 \mu\text{F}$		0.3		ms
t _f	Output fall time	$V_I = 2.7 \text{ V},$ $R_L = 10 \Omega,$ $C_L = 1 \mu F$		0.2		ms
T _{ON}	Turn-ON time ⁽¹⁾	R_L = 10 Ω C_L = 100 μF			20	ms
T _{OFF}	Turn-OFF time ⁽¹⁾	$\begin{aligned} R_L &= 10 \ \Omega \\ C_L &= 100 \ \mu F \end{aligned}$			40	ms

Not tested in production, specified by design

Table 6. Current limit characteristics $(V_I = 5.5 \text{ V}, I_O = \text{rated current}, T_J = 25 ^{\circ}\text{C}, \text{ unless otherwise specified})$

Symbol	Parameter	Test conditions	Min	Тур	Max	Unit
I _{OS}	Short-circuit output current	V _I = 5 V, OUT connected to GND, device enabled into short-circuit	0.7	1.0	1.3	Α

ST2051 Electrical characteristics

Table 7. Supply current characteristics $(V_I = 5.5 \text{ V}, I_O = \text{rated current}, T_J = 25 ^{\circ}\text{C}, \text{ unless otherwise specified})$

Symbol	Parameter	Test conditions	Min	Тур	Max	Unit
1	Switch turned OFF	No load		1.0	5.0	μΑ
IOFF	Switch turned OFF	No load; -40 < T _J < 125 °C			10	μΑ
1.	Switch turned ON	No load		70	90	μΑ
ION		No load; -40 < T _J < 125 °C			100	μΑ
		Output grounded, switch is OFF			10	μΑ
I _{leakage}	Output leakage current	Output grounded, switch is OFF; -40 < T _J < 125 °C			20	μА

Table 8. Thermal characteristics $(V_I = 5.5 \text{ V}, I_O = \text{rated current}, T_J = 25 ^{\circ}\text{C}, \text{ unless otherwise specified})$

Symbol	Parameter	Test conditions	Min	Тур	Max	Unit
T1	Thermal shutdown threshold		135)		°C
T2	Recovery from thermal shutdown	40.	125			°C
Hyst	Hysteresis	16,10		10		°C

Table 9. UVLO characteristics $(V_I = 5.5 \text{ V}, I_O = \text{rated current}, T_J = 25 ^{\circ}\text{C}, \text{ unless otherwise specified})$

Symbol	Parameter	Test conditions	Min	Тур	Max	Unit
V _{UVLO}	Undervoltage lockout threshold		2.0		2.5	٧
Hyst	Hysteresis			100		mV

Table 10. OC pin characteristics $(V_I = 5.5 \text{ V}, I_O = \text{rated current}, T_J = 25 ^{\circ}\text{C}, \text{ unless otherwise specified})$

Symbol	Parameter	Test conditions	Min	Тур	Max	Unit
OC blanking	OCx assertion and de-assertion ⁽¹⁾		4	8	15	ms
Vo	Output low voltage				0.4	V
I _{OFF}	OFF current				1.0	μА

^{1.} Not tested in production, specified by design.

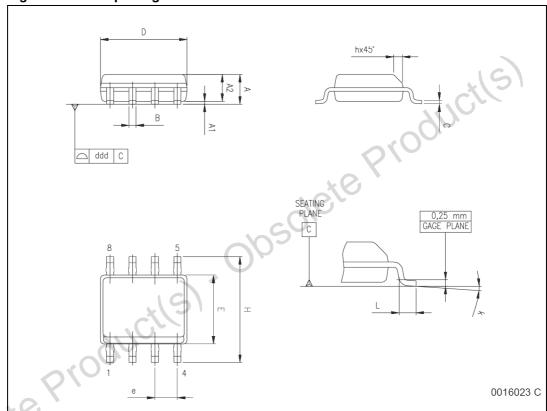
Table 11. EN pin characteristics $(V_I = 5.5 \text{ V}, I_O = \text{rated current}, T_J = 25 ^{\circ}\text{C}, \text{ unless otherwise specified})$

Symbol	Parameter	Test conditions	Min	Тур	Max	Unit
V _{IH}	High level input voltage	V _I = 2.7 to 5.5 V	2.0			V
V		V _I = 4.5 to 5.5 V			0.8	V
V _{IL}	Low level input voltage	V _I = 2.7 to 4.5 V			0.4	V
I _I	Input current	V _{IENX} = 0 or V _I	-0.5		0.5	μΑ

6 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

Figure 3. SO-8 package outline



ST2051 Revision history

Table 12. SO-8 mechanical data

Counched		Millimeters			inches	
Symbol	Min	Тур	Max	Min	Тур	Max
Α	1.35		1.75	0.053		0.069
A1	0.10		0.25	0.004		0.010
A2	1.10		1.65	0.043		0.065
В	0.33		0.51	0.013		0.020
С	0.19		0.25	0.007		0.010
D	4.80		5.00	0.189		0.197
Е	3.80		4.00	0.15	·C	0.157
е		1.27			0.050	
Н	5.80		6.20	0.228	100	0.244
h	0.25		0.50	0.010		0.020
L	0.40		1.27	0.016		0.050
k			8° (n	nax.)		
ddd			0.10			0.004

7 Revision history

Table 13. Document revision history

Date	Revision	Changes
02-Aug-2006	1	Initial release.
26-Feb-2008	2	Document restructured and converted to new ST template, watermark removed.
24-Nov-2010	3	Document reformatted, added "Not Recommended for New Design" and <i>Note 1</i> below <i>Table 1</i> , corrected typo in <i>Features</i> , <i>Description</i> , <i>Section 3</i> , <i>Section 4</i> , <i>Table 3</i> , <i>Table 5</i> to <i>Table 11</i> , updated ECOPACK® text in <i>Section 6</i> .

Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZED ST REPRESENTATIVE, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2010 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Philippines - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com

10/10 Doc ID 12593 Rev 3

